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Kind regards,

Team Nexperia



PESD1IVN-U

In-vehicle network ESD protection diode

15 July 2015

Product data sheet

1. General description

ElectroStatic Discharge (ESD) protection diode in a small SOT323 (SC-70) Surface-Mounted Device (SMD) plastic package designed to protect one automotive in-vehicle network line from the damage caused by ESD and other transients.

2. Features and benefits

- One small SOT323 package to protect one in-vehicle network line
- Low clamping voltage: V_{CL} = 38 V at I_{PP} = 1 A
- ESD protection up to 18 kV; IEC 61000-4-2, level 4
- IEC 61000-4-5 (surge); I_{PP} = 3 A at t_p = 8/20 μ s
- AEC-Q101 qualified

3. Applications

- In-vehicle network ESD protection for CAN, LIN, FlexRay and Single Edge Nibble Transmission (SENT) interfaces
- Generic automotive applications

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{RWM}	reverse standoff voltage	T _{amb} = 25 °C	-	-	26.5	V
C _d	diode capacitance	$f = 1 \text{ MHz}$; $V_R = 0 \text{ V}$; $T_{amb} = 25 ^{\circ}\text{C}$	-	8.5	11	pF

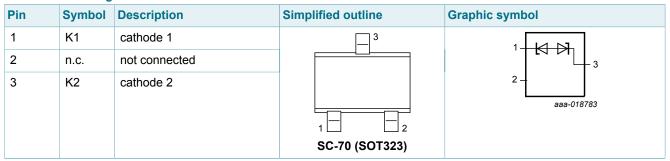




In-vehicle network ESD protection diode

5. Pinning information

Table 2. Pinning information



6. Ordering information

Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
PESD1IVN-U	SC-70	plastic surface-mounted package; 3 leads	SOT323		

7. Marking

Table 4. Marking codes

3 - 1 - 1	
Type number	Marking code
	[1]
PESD1IVN-U	3X%

[1] % = placeholder for manufacturing site code

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8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

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Symbol	Parameter	Conditions		Min	Max	Unit
P_{PPM}	rated peak pulse power	t _p = 8/20 μs	[1][2]	-	150	W
I _{PPM}	rated peak pulse current		[1][2]	-	3	Α
T _j	junction temperature			-	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C
ESD maximu	m ratings					
V _{ESD}	electrostatic discharge voltage	IEC 61000-4-2; contact discharge	[2][3]	-	18	kV
		MIL-STD-883 (human body model)	[2][3]	-	10	kV

Non-repetitive current pulse 8/20 μs exponential decay waveform according to IEC 61000-4-5 and IEC 61643-321.

- [2] Measured from pin 1 to 3.
- [3] Device stressed with ten non-repetitive ESD pulses.

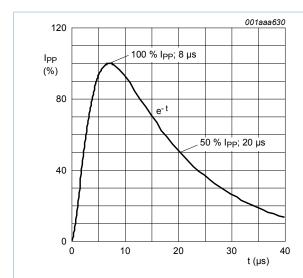


Fig. 1. 8/20 μs pulse waveform according to IEC 61000-4-5 and IEC 61643-321

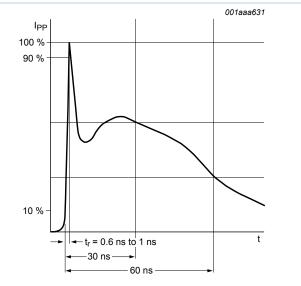
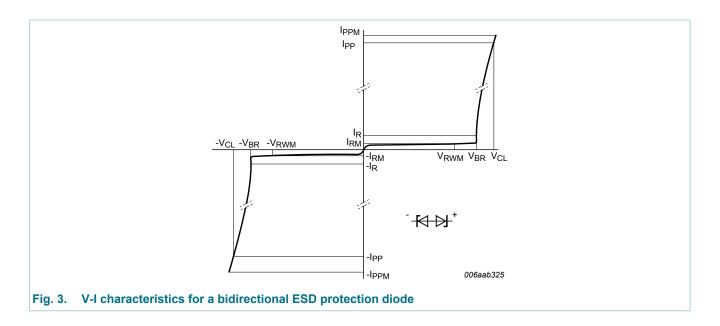


Fig. 2. ESD pulse waveform according to IEC 61000-4-2

In-vehicle network ESD protection diode



9. Characteristics

Table 6. Characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V_{RWM}	reverse standoff voltage	T _{amb} = 25 °C		-	-	26.5	V
I _{RM}	reverse leakage current	V _{RWM} = 26.5 V; T _{amb} = 25 °C		-	1	50	nA
V_{BR}	breakdown voltage	I _R = 5 mA; T _{amb} = 25 °C		28	30	32	V
C _d	diode capacitance	f = 1 MHz; V _R = 0 V; T _{amb} = 25 °C		-	8.5	11	pF
		$f = 1 \text{ MHz}$; $V_R = 2.5 \text{ V}$; $T_{amb} = 25 ^{\circ}\text{C}$		-	6.6	-	pF
V_{CL}	clamping voltage	I _{PP} = 1 A; T _{amb} = 25 °C	[1][2]	-	-	38	V
		I _{PPM} = 3 A; T _{amb} = 25 °C	[1][2]	-	-	53	V
R _{dyn}	dynamic resistance	I _R = 20 A; T _{amb} = 25 °C	[3]	-	2	-	Ω

Non-repetitive current pulse 8/20 μs exponential decay waveform according to IEC 61000-4-5 and IEC 61643-321.

^[2] Measured from pin 1 to 3.

^[3] Non-repetitive current pulse, Transmission line Pulse (TLP), square pulse, ANSI/ESD STM5.5.1-2008.

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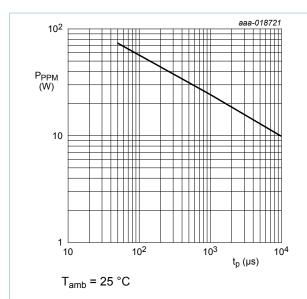


Fig. 4. Rated peak pulse power as a function of square pulse duration; typical values

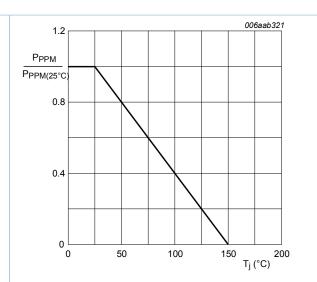
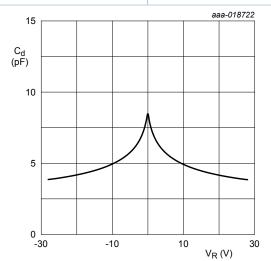


Fig. 5. Relative variation of rated peak pulse power as a function of junction temperature; typical values

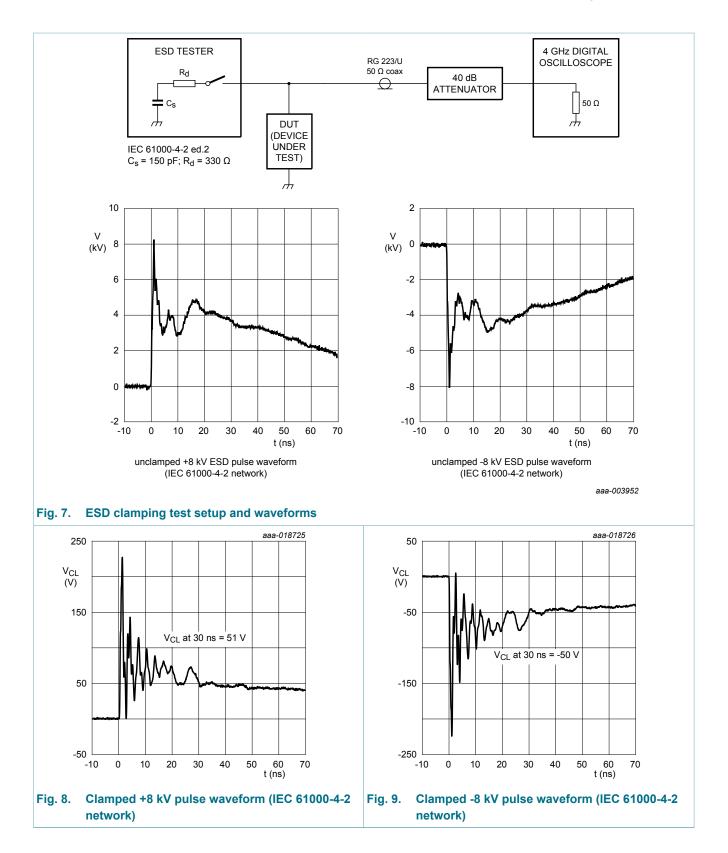


 $f = 1 \text{ MHz}; T_{amb} = 25 \text{ °C}$

Fig. 6. Diode capacitance as a function of reverse voltage; typical values

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In-vehicle network ESD protection diode



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10. Application information

The device is designed for the protection of one automotive in-vehicle network bus line from surge pulses and ESD damage. The device provides a surge capability of up to 3 A for an $8/20~\mu s$ waveform.

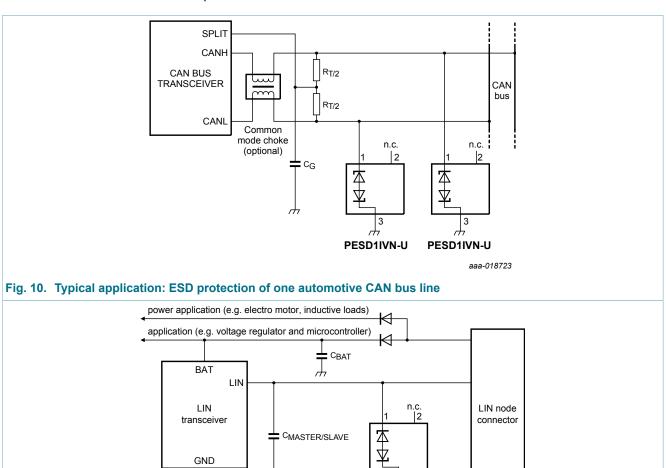


Fig. 11. Typical application: ESD protection of one automotive LIN bus line

Circuit board layout and protection device placement

Circuit board layout is critical for the suppression of ESD, Electrical Fast Transient (EFT) and surge transients. The following guidelines are recommended:

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- 1. Place the device as close to the input terminal or connector as possible.
- 2. Minimize the path length between the device and the protected line.
- 3. Keep parallel signal paths to a minimum.
- 4. Avoid running protected conductors in parallel with unprotected conductors.
- Minimize all Printed-Circuit Board (PCB) conductive loops including power and ground loops.
- 6. Minimize the length of the transient return path to ground.

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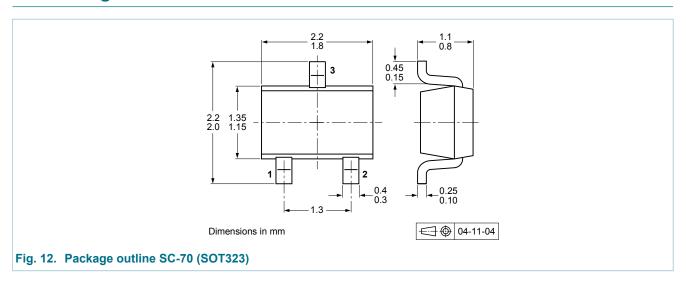
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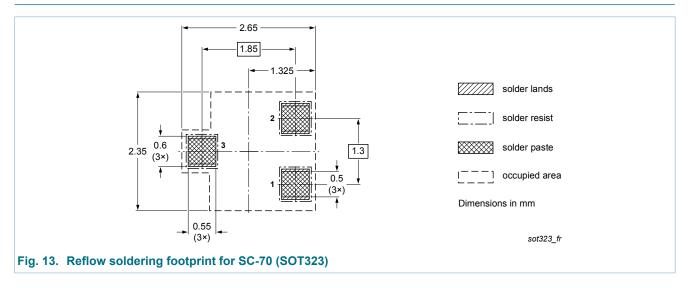
In-vehicle network ESD protection diode

- 7. Avoid using shared transient return paths to a common ground point.
- 8. Use ground planes whenever possible. For multilayer PCBs, use ground vias.

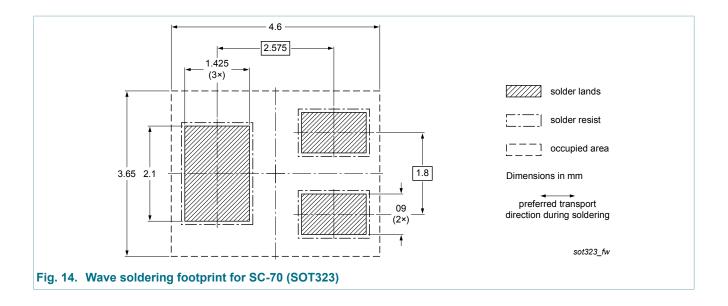
11. Package outline



12. Soldering



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13. Revision history

Table 7. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PESD1IVN-U v.1	20150715	Product data sheet	-	-

In-vehicle network ESD protection diode

14. Legal information

14.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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Date of release: 15 July 2015